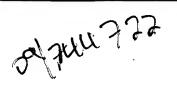
	From the INTERNATIONAL BUREAU			
PCT	То:			
NOTIFICATION OF THE RECORDING OF A CHANGE (PCT Rule 92bis.1 and Administrative Instructions, Section 422) Date of mailing (day/month/year) 10 July 2000 (10.07.00)	AGFA-GEVAERT N.V. Attn.:Van Ostaeyen, Marc Corporate IP Department Septestraat 27 B-2640 Mortsel BELGIQUE			
Applicant's or agent's file reference A-G 6564-PC Jo	IMPORTANT NOTIFICATION			
International application No. PCT/EP99/05147	International filing date (day/month/year) 20 July 1999 (20.07.99)			
The following indications appeared on record concerning: The applicant the inventor	the agent the common representative			
Name and Address	State of Nationality State of Residence DE DE			
AGFA-GEVAERT AG Kaiser-Wilhelm-Allee D-51373 Leverkusen Germany	Telephone No.			
Germany	Facsimile No.			
	Teleprinter No.			
2. The International Bureau hereby notifies the applicant that t	the following change has been recorded concerning:			
the person X the name X the add	Idress X the nationality X the residence			
Name and Address	State of Nationality State of Residence BE BE			
AGFA-GEVAERT NAAMLOZE VENNOOTSCHAP Septestraat 27 B-2640 Mortsei	Telephone No.			
Belgium	Facsimile No.			
	Teleprinter No.			
3. Further observations, if necessary:				
4. A copy of this notification has been sent to:				
X the receiving Office	the designated Offices concerned			
the International Searching Authority	X the elected Offices concerned			
the International Preliminary Examining Authority	other:			
TI LA WARENERS (MIRO	Authorized officer			
The International Bureau of WIPO 34, chemin des Colombettes	A. Karkachi			
1211 Geneva 20, Switzerland Facsimile No.: (41-22) 740.14.35	Telephone No.: (41-22) 338.83.38			

From the INTERNATIONAL BUREAU

PCT	То:				
NOTIFICATION OF THE RECORDING OF A CHANGE (PCT Rule 92bis.1 and Administrative Instructions, Section 422) Date of mailing (day/month/year) 10 July 2000 (10.07.00)	AGFA-GEVAERT N.V. Attn.:Van Ostaeyen, Marc Corporate IP Department Septestraat 27 B-2640 Mortsel BELGIQUE				
Applicant's or agent's file reference A-G 6564-PC Jo			IMPORTANT NOTI	IFICATION	
International application No. PCT/EP99/05147			onal filing date (day/month/yelluly 1999 (20.07.99)	ear)	
The following indications appeared on record concern the applicant the inventor	ing:	the ager	nt X the commo	on representative	
Name and Address AGFA-GEVAERT AG Kaiser-Wilhelm-Allee			State of Nationality	State of Residence	
D-51373 Leverkusen Germany			Telephone No. 0214 30 71166		
			Facsimile No. 0214 30 534 82		
			Teleprinter No.		
2. The International Bureau hereby notifies the applicant the person the name X the	t that the		the nationality	concerning: X the residence	
Name and Address AGFA-GEVAERT N.V.			State of Nationality	State of Residence	
Attn.:Van Ostaeyen, Marc Corporate IP Department Septestraat 27			Telephone No.	<u> </u>	
B-2640 Mortsel Belgium		Ì	Facsimile No.		
		Teleprinter No.			
3. Further observations, if necessary:					
4. A copy of this notification has been sent to:					
X the receiving Office		Г	the designated Offices of	concerned	
the International Searching Authority		Ī	X the elected Offices conc		
X the International Preliminary Examining Authority			other:		
The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland	-	Authorized (officer A. Karkachi		

Facsimile No.: (41-22) 740.14.35 Telephone No.: (41-22) 338.83.38



PATENT COOPERATION TREATY



From the INTERNATIONAL BUREAU

PCT

NOTIFICATION OF ELECTION

(PCT Rule 61.2)

Assistant Commissioner for Patents United States Patent and Trademark

Office **Box PCT**

Washington, D.C.20231 **ETATS-UNIS D'AMERIQUE**

Date of mailing (day/month/year)	П	
27 March 2000 (27.03.00)	П	in its capacity as elected Office

International application No. PCT/EP99/05147

International filing date (day/month/year)

20 July 1999 (20.07.99)

Applicant's or agent's file reference A-G 6564-PC Jo

Priority date (day/month/year) 30 July 1998 (30.07.98)

Applicant

CRONE, Klaus-Peter et al

1.	The designated Office is hereby notified of its election made:
	X in the demand filed with the International Preliminary Examining Authority on:
	04 February 2000 (04.02.00)
	in a notice effecting later election filed with the International Bureau on:
2.	The election X was was not was not made before the expiration of 19 months from the priority date or, where Rule 32 applies, within the time limit under Rule 32.2(b).

The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland

Authorized officer

R. E. Stoffel

Telephone No.: (41-22) 338.83.38

Facsimile No.: (41-22) 740.14.35





RDM/IP-LEV Dr. A. Jochum

Ema: 2 2. Feb. 2000

PCT

From the INTERNATIONAL BUREAU

AGFA-GEVAERT AG Kaiser-Wilhelm-Allee D-51373 Leverkusen ALLEMAGNE

NOTICE INFORMING THE APPLICANT OF THE COMMUNICATION OF THE INTERNATIONAL APPLICATION TO THE DESIGNATED OFFICES

(PCT Rule 47.1(c), first sentence)

Date of mailing (day/month/year)

10 February 2000 (10.02.00)

Applicant's or agent's file reference

A-G 6564-PC Jo International application No.

PCT/EP99/05147

international filing date (day/month/year) 20 July 1999 (20.07.99)

Priority date (day/month/year) 30 July 1998 (30.07.98)

IMPORTANT NOTICE

Applicant

AGFA-GEVAERT AG et al

 Notice is hereby given that the International Bureau has communicated, as provided in Article 20, the international application to the following designated Offices on the date indicated above as the date of mailing of this Notice: AU, CN, EP, IL, JP, KP, KR, US

In accordance with Rule 47.1(c), third sentence, those Offices will accept the present Notice as conclusive evidence that the communication of the international application has duly taken place on the date of mailing indicated above and no copy of the international application is required to be furnished by the applicant to the designated Office(s).

2. The following designated Offices have waived the requirement for such a communication at this time:

AE,AL,AM,AP,AT,AZ,BA,BB,BG,BR,BY,CA,CH,CU,CZ,DE,DK,EA,EE,ES,FI,GB,GD,GE,GH,GM,HR, HU,ID,IN,IS,KE,KG,KZ,LC,LK,LR,LS,LT,LU,LV,MD,MG,MK,MN,MW,MX,NO,NZ,OA,PL,PT,RO,RU, SD,SE,SG,SI,SK,SL,TJ,TM,TR,TT,UA,UG,UZ,VN,YU,ZA,ZW
The communication will be made to those Offices only upon their request. Furthermore, those Offices do not require the

applicant to furnish a copy of the international application (Rule 49.1(a-bis)).

3. Enclosed with this Notice is a copy of the international application as published by the International Bureau on 10 February 2000 (10.02.00) under No. WO 00/07250

REMINDER REGARDING CHAPTER II (Article 31(2)(a) and Rule 54.2)

If the applicant wishes to postpone entry into the national phase until 30 months (or later in some Offices) from the priority date, a demand for international preliminary examination must be filed with the competent International Preliminary Examining Authority before the expiration of 19 months from the priority date.

It is the applicant's sole responsibility to monitor the 19-month time limit.

Note that only an applicant who is a national or resident of a PCT Contracting State which is bound by Chapter II has the right to file a demand for international preliminary examination.

REMINDER REGARDING ENTRY INTO THE NATIONAL PHASE (Article 22 or 39(1))

If the applicant wishes to proceed with the international application in the national phase, he must, within 20 months or 30 months, or later in some Offices, perform the acts referred to therein before each designated or elected Office.

For further important information on the time limits and acts to be performed for entering the national phase, see the Annex to Form PCT/IB/301 (Notification of Receipt of Record Copy) and Volume II of the PCT Applicant's Guide.

The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland

Authorized officer

J. Zahra

Facsimile No. (41-22) 740.14.35

Telephone No. (41-22) 338.83.38

Form PCT/IB/308 (July 1998)

3084970

PCT

REQUEST

The undersigned requests that the present international application be processed according to the Patent Cooperation Treaty.

For receiving O	ffice use only
PCT/E International Application No.	P 99/0514:
2 0 JUL 1999 International Filing Date	(2 0. 07. 1999)
EUROPEAN PAT PCT INTERNATION Name of receiving Office and "PCT	ONAL APPLICATION

Applicant's or agent's file reference

•	Applicant's or agent's file reference (if desired) (12 characters maximum) A-G 6564-PC Jo							
Box No. I TITLE OF INVENTION								
"Method of producing solar cells"								
Box No. II APPLICANT								
Name and address: (Family name followed by given name; for designation. The address must include postal code and name of caddress indicated in this Box is the applicant's State (that is, coun of residence is indicated below.)	a legal entity, full official country. The country of the try) of residence if no State. This person is also inventor.							
3 755 2 5115	Telephone No.							
Agfa-Gevaert AG	0214 30 71166							
.Kaiser-Wilhelm-Allee D 51373 Leverkusen	Facsimile No.							
DE	0214 30 534 82							
	Teleprinter No. 85 101-265byd							
State (that is, country) of nationality:	State (that is, country) of residence:							
DE	DE							
This person is applicant all designated for the purposes of:	nated States except the United States of the States indicated in of America only the Supplemental Box							
Box No. III FURTHER APPLICANT(S) AND/OR (FUR								
Name and address: (Family name followed by given name; for a legal entity, full official designation. The address must include postal code and name of country. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below.) This person is: applicant only								
Crone, Klaus-Peter Im Bungert 4	X applicant and inventor							
D 53773 Hennef DE	inventor only (If this check-box is marked, do not fill in below.)							
State (that is, country) of nationality:	State (that is, country) of residence: DE.							
This person is applicant all designated all designated	nated States except							
X Further applicants and/or (further) inventors are indicate	ed on a continuation sheet.							
Box No. IV AGENT OR COMMON REPRESENTATION	IVE; OR ADDRESS FOR CORRESPONDENCE							
The person identified below is hereby/has been appointed to a of the applicant(s) before the competent International Authority	The person identified below is hereby/has been appointed to act on behalf of the applicant(s) before the competent International Authorities as:							
Name and address: (Family name followed by given name; for designation. The address must include posta	al code and name of country.)							
Agfa-Gevaert AG	0214 30 71166							
Kaiser-Wilhelm-Allee	Facsimile No.							
D 51373 Leverkusen	0214 30 534 82							
DE	Teleprinter No.							
	85 101-265-byd							
Address for correspondence: Mark this check-box wh	ere no agent or common representative is/has been appointed and the							

Sheet No. ... 2...

Continuation of Box No. II	I FURTHER A	PPLICANT(S) A	ND/OR (FURT	HER) IN	ENTOR(S)	
	of the following sul	b-boxes is used, thi	s sheet should r	not be incl	uded in the re	quest
Name and address: (Family designation. The address mus address indicated in this Box of residence is indicated bell Löffelmann, Gi Am Domberg 9 D 51515 Kürter DE	inter	ven name: for a le and name of count te (that is, country)	egal entity, full a ry. The country of residence if no	official of the State	x applic	is: ant only ant and inventor or only (If this check-box ked, do not fill in below.)
State (that is, country) of na	tionality:		State (that is, o			
This person is applicant for the purposes of:	all designated States	all designated the United Sta	States except tes of America	X the	United States America only	the States indicated in the Supplemental Box
Name and address: (Family designation. The address mus address indicated in this Box of residence is indicated be. Modemenn, Kar Heinrich-Hein D 53225 Bonn DE	1. 1	iven name; for a l e and name of count ue (that is, country)			X applic	is: ant only ant and inventor or only (If this check-bax ked, do not fill in below.)
State (that is, country) of n	ationality:	-	State (that is,	country) 0	f residence:	
This person is applicant for the purposes of:	all designated States	all designated the United St	States except ates of America	the of	United States America only	the States indicated in the Supplemental Box
Name and address: (Family designation. The address maddress indicated in this Box of residence is indicated be Koch, Eberhar Königsberger D 51399 Burso DE	d Str. 34	iven name: for a le and name of coun ate (that is, country)	legal entity, full try. The country of residence if n	official of the w State	x appli	n is: cant only cant and inventor ntor only (If this check-box arked, do not fill in below.)
State (that is, country) of I	nationality:		State (that is,	, country)	of residence:	
This person is applicant for the purposes of:	all designated	all designate the United S	d States except tates of America		e United States America only	the States indicated in the Supplemental Box
Name and address: (Famili designation. The address in dicated in this Bo of residence is indicated by Sauerteig, Wolter-Flex-SD 51373 Level DE	ust include postal co x is the applicant's S elow.) olfgang Str. 1				X appl	on is: icant only icant and inventor entor only (If this check-box earked, do not fill in below.)
State (that is, country) of DE	nationality:		State (that is	country)	of residence:	
This person is applicant for the purposes of:	all designates	d all designate the United	ed States except States of America		the United State of America only	
Further applicants	and/or (further) inv	entors are indicated	on another con	tinuation s	heeL	

Form PCT/RO/101 (continuation sheet) (July 1998)

See Notes to the request form

DESIGNATION OF STATES Box No.V The following designations are hereby made under Rule 4.9(a) (mark the applicable check-boxes; at least one must be marked): Regional Patent ARIPO Patent: GH Ghana, GM Gambia, KE Kenya, LS Lesotho, MW Malawi, SD Sudan, SZ Swaziland, UG Uganda, 図 ZW Zimbabwe, and any other State which is a Contracting State of the Harare Protocol and of the PCT Eurasian Patent: AM Armenia, AZ Azerbaijan, BY Belarus, KG Kyrgyzstan, KZ Kazakhstan, MD Republic of Moldova, RU Russian Federation, TJ Tajikistan, TM Turkmenistan, and any other State which is a Contracting State of the Eurasian Patent Convention and of the PCT European Patent: AT Austria, BE Belgium, CH and LI Switzerland and Liechtenstein, CY Cyprus, DE Germany, DK Denmark, ES Spain, FI Finland, FR France, GB United Kingdom, GR Greece, IE Ireland, IT Italy, LU Luxembourg, MC Monaco, NL Netherlands, PT Portugal, SE Sweden, and any other State which is a Contracting State of the European Patent Convention and of the PCT OA OAPI Patent: BF Burkina Faso, BJ Benin, CF Central African Republic, CG Congo, CI Côte d'Ivoire, CM Cameroon, GA Gabon, GN Guinea, ML Mali, MR Mauritania, NE Niger, SN Senegal, TD Chad, TG Togo, and any other State M Colded ! which is a member State of OAPI and a Contracting State of the PCT (if other kind of protection or treatment desired, specify on dotted line) & GW Guinea Bissian . Rallo National Patent (if other kind of protection or treatment desired, specify on dotted line): LS Lesotho AL Albania X LT Lithuania AM Armenia Austria 図 LU Luxembourg 図 LV Latvia X ΑÜ 囟 MD Republic of Moldova Azerbaijan X AZ MG Madagascar Bosnia and Herzegovina M BA MK The former Yugoslav Republic of Macedonia ... \boxtimes \mathbf{BB} Barbados ************* BG Bulgaria X 図 MN Mongolia X BR Brazil MW Malawi X MX Mexico X Canada K NO Norway CH and LI Switzerland and Liechtenstein X New Zealand CN China \mathbf{z} Poland CU Cuba Portugal PT Czech Republic X CZ RO Romania DE Germany..... M Russian Federation \boxtimes RU DK Denmark.... X Sudan Estonia Ø SD M EE SE Sweden X ES 図 SG Singapore X FI Slovenia X Ø GB United Kingdom Slovakia Ø SK Georgia Ø GE 凶 Sierra Leone SL GH Ghana \boxtimes Tajikistan TJ M GM Gambia Turkmenistan X TM C-**X** GW Guinea-Bisser Turkey TR 卤 HR Croatia Trinidad and Tobago X TT Hungary X HU Ukraine X UA B ID Indonesia Uganda X UG $oldsymbol{\Xi}$ IL Israel X $oldsymbol{\boxtimes}$ IS Japan \boxtimes JP Uzbekistan UZ Z KE VN Viet Nam X KG Kyrgyzstan YU Yugoslavia Democratic People's Republic of Korea ZW Zimbabwe Check-boxes reserved for designating States (for the purposes of a national patent) which have become party to the PCT after issuance of this sheet: GO IN AE ZA have KR Republic of Korea a Joled 囡 Rolep $oldsymbol{\boxtimes}$ Saint Lucia PCT-by (asoeded to the and X LK Sri Lanka <u>Filing date of this application</u> × LR Liberia

Precautionary Designation Statement: In addition to the designations made above, the applicant also makes under Rule 4.9(b) all other designations which would be permitted under the PCT except any designation(s) indicated in the Supplemental Box as being excluded from the scope of this statement. The applicant declares that those additional designations are subject to confirmation and that any designation which is not confirmed before the expiration of 15 months from the priority date is to be regarded as withdrawn by the applicant at the expiration of that time limit. (Confirmation of a designation consists of the filing of a notice specifying that designation and the payment of the designation and confirmation fees. Confirmation must reach the receiving Office within the 15-month time limit.)

Supplemental Box

If the Supplemental Box is not used, this sheet should not be included in the request.

- 1. If, in any of the Boxes, the space is insufficient to furnish all the information. in such case, write "Continuation of Box No. ..." [indicate the number of the Box] and furnish the information in the same manner as required according to the captions of the Box in which the space was insufficient, in particular:
- (i) if more than two persons are involved as applicants and/or inventors and no "continuation sheet" is available: in such case, write "Continuation of Box No. III" and indicate for each additional person the same type of information as required in Box No. III. The country of the address indicated in this Box is the applicant's State (that is, country) of residence if no State of residence is indicated below;
- (ii) if, in Box No. II or in any of the sub-boxes of Box No. III, the indication "the States indicated in the Supplemental Box" is checked: in such case, write "Continuation of Box No. II" or "Continuation of Box No. III" or "Continuation of Boxes No. II and No. III" (as the case may be), indicate the name of the applicant(s) involved and, next to (each) such name, the State(s) (and/or, where applicable, ARIPO, Eurasian, European or OAPI patent) for the purposes of which the named person is applicant;
- (iii) if, in Box No. II or in any of the sub-boxes of Box No. III, the inventor or the inventor/applicant is not inventor for the purposes of all designated States or for the purposes of the United States of America: in such case, write "Continuation of Box No. II" or "Continuation of Box No. III" or "Continuation of Boxes No. II and No. III" (as the case may be), indicate the name of the inventor(s) and, next to (each) such name, the State(s) (and/or, where applicable, ARIPO, Eurosian, European or OAPI patent) for the purposes of which the named person is inventor;
- (iv) if, in addition to the agent(s) indicated in Box No. IV, there are further agents: in such case, write "Continuation of Box No. IV" and indicate for each further agent the same type of information as required in Box No. IV:
- (v) if, in Box No. V, the name of any State (or OAPI) is accompanied by the indication "patent of addition," or "certificate of addition," or if, in Box No. V, the name of the United States of America is accompanied by an indication "continuation" or "continuation-in-part": in such case, write "Continuation of Box No. V" and the name of each State involved (or OAPI), and after the name of each such State (or OAPI), the number of the parent title or parent application and the date of grant of the parent title or filing of the parent application:
- (vi) If, in Box No. VI, there are more than three earlier applications whose priority is claimed: in such case, write "Continuation of Box No. VI" and indicate for each additional earlier application the same type of information as required in Box No. VI;
- (vii) if, in Box No. VI, the earlier application is an ARIPO application: in such case, write "Continuation of Box No. VI", specify the number of the item corresponding to that earlier application and indicate at least one country party to the Paris Convention for the Protection of Industrial Property for which that earlier application was filed.
- 2. If, with regard to the precautionary designation statement contained in Box No. V, the applicant wishes to exclude any State(s) from the scope of that statement: In such case, write "Designation(s) excluded from precautionary designation statement" and indicate the name or two-letter code of each State so excluded.
- 3. If the applicant claims, in respect of any designated Office, the benefits of provisions of the national law concerning non-prejudicial disclosures or exceptions to lack of novelty: in such case, write "Statement concerning non-prejudicial disclosures or exceptions to lack of novelty" and furnish that statement below.

Continuation of Box No. IX

A-G 6564-PC		Si	heet No					
	AIM .		[Further prio	rity claims are indicated	in the Supplemental Box.		
Doart		ımber			Where earlier applicati	on is:		
Filing date of earlier application (day/month/year)		application	1	application: ountry	regional application:* regional Office	international application: receiving Office		
item (1)					Ì			
(30.7.98)				DE				
30 Juli 1998	198	358.2	 	<u> </u>				
item (2)								
			<u> </u>					
item (3)								
of the earlier application	The receiving Office is requested to prepare and transmit to the International Bureau a certified copy of the earlier application(s) (only if the earlier application was filed with the Office which for the purposes of the present international application is the receiving Office) identified above as item(s):							
• Where the earlier application I Convention for the Protection of	s an ARIPO i Industrial Pri	application, it is operty for which	mandatory t that earlier	o indicate in the application was	Supplemental Box at least filed (Rule 4.10(b)(ii)). Se	one country party to the Paris e Supplemental Box.		
Box No. VII INTERNATI			THORIT	<u> </u>	I'm accords reference	e to that search (if an earlier		
Choice of International Sear (if two or more International S competent to carry out the inter the Authority chosen; the two-le	mational seas	horities are se	lequest to t earch has be Date (day/mi	en carried out by	or requested from the Inte	rnational Searching Authority): Country (or regional Office)		
ISA /				<u> </u>				
Box No. VIII CHECK LI	ST; LANG	UAGE OF FI	LING					
This international application the following number of she	contains	This internation	onal applica		anled by the item(s) ma	rked below:		
request :	5			ower of attorney	v			
description (excluding sequence listing part)	4	2.	te signed po of general p	ower of attorne	y; reference number, if	any:		
claims :	1	4. Statem	ent explain	ing lack of sign	ature			
abstract :	1	5. 🔀 priorit	y documen	t(s) identified it	n Box No. VI as itcm(s):			
drawings :		6. 🔲 transla	ation of inte	mational applic	cation into (language):			
sequence listing part	•	7. Separa	ne indicatio	ns concerning	deposited microorganism	or other biological material		
of description :		0		amina acid sec	mence listing in comput	er readable form		
Total number of sheets:	11	9. 🔀 other	(specify): [ebit or	der, Demand i	for publication		
Figure of the drawings who should accompany the abstr	ich		Language	of filing of the	CUUICS			
		LICANT OR						
Box No. IX SIGNATUR	KE OF APP	Dereve signing on	d the capacit	in which the pers	on signs (if such capacity is n	or obvious from reading the request)		
Next to each signature, indicate to	ne name oj us	person signalig all		, <u></u> - ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		•		
				for	further sign	atures		
AGFA-GEVA	ERI AG	•		plea	se see suppl	emental		
1 /2 /	. /			shee	t 4 (will fo	T10M) +		
1/2/11	\sim .							
1 Jams.	{					•		
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			For receiving	g Office use on	nly			
Date of actual receipt of international application	of the purpor			IŬL 1999	(20.07.99)	2. Drawings:		
3. Corrected date of actua	d receipt due	completing				received:		
the purported internation 4. Date of timely receipt corrections under PCT						not received		
5. International Searching (if two or more are con	Authority			6. Tran	smittal of search copy de search fee is paid.	:layed		
(11.170 01.14010 120.001		·	_ Intomostic	nal Bureau usc	only			
Dan of marine of the mar	ord con:	F0	i inicmado	nar Dolean næ	,			
Date of receipt of the receipt of the International Bure	au:							
		000)				See Notes to the request for		

Form PCT/RO/101 (last sheet) (July 1998)

From the INTERNATIONAL PRELIMINARY EXAMINING AUTHORITY

AGFA-GEVAERT N.V. Attn.:Van Ostaeyen, Marc Corporate IP Department Septestraat 27 B-2640 Mortsel BELGIQUE

NOTIFICATION OF TRANSMITTAL OF THE INTERNATIONAL PRELIMINARY **EXAMINATION REPORT** (PCT Rule 71.1)

Date of mailing

(day/month/year)

03.10.2000

Applicant's or agent's file reference

A-G 6564-PC Jo

IMPORTANT NOTIFICATION

International application No. PCT/EP99/05147

International filing date (day/month/year)

Priority date (day/month/year) 30/07/1998

20/07/1999

Applicant

AGFA-GEVAERT NAAMLOZE VENNOOTSCHAP et al.

- 1. The applicant is hereby notified that this International Preliminary Examining Authority transmits herewith the international preliminary examination report and its annexes, if any, established on the international application.
- 2. A copy of the report and its annexes, if any, is being transmitted to the International Bureau for communication to all the elected Offices.
- 3. Where required by any of the elected Offices, the International Bureau will prepare an English translation of the report (but not of any annexes) and will transmit such translation to those Offices.

4. REMINDER

The applicant must enter the national phase before each elected Office by performing certain acts (filing translations and paying national fees) within 30 months from the priority date (or later in some Offices) (Article 39(1)) (see also the reminder sent by the International Bureau with Form PCT/IB/301).

Where a translation of the international application must be furnished to an elected Office, that translation must contain a translation of any annexes to the international preliminary examination report. It is the applicant's responsibility to prepare and furnish such translation directly to each elected Office concerned.

For further details on the applicable time limits and requirements of the elected Offices, see Volume II of the PCT Applicant's Guide.

Name and mailing address of the IPEA/

Authorized officer

Sinanovic, E

European Patent Office - P.B. 5818 Patentlaan 2 NL-2280 HV Rijswijk - Pays Bas

Tel. +31 70 340 - 2040 Tx: 31 651 epo nl

Fax: +31 70 340 - 3016

Tel.+31 70 340-2672



PATENT COOPERATION TREATY

PCT

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

Applicantia)r 200	nt's file reference							
A-G 6564	_		FOR FURTHER ACTION	See Notification of Transmittal or Preliminary Examination Report					
Internationa	appli	cation No.	International filing date (day/month	year) Priority date (day/n	nonth/year)				
PCT/EP9	9/05	147	20/07/1999	30/07/1998					
H01L31/1	8		iional classification and IPC						
AGFA-GE	VAE	RT NAAMLOZE VEN	NOOTSCHAP et al.						
		ational preliminary exami smitted to the applicant a	nation report has been prepared coording to Article 36.	by this International Prelimina	ary Examining Authority				
2. This F	EPO	RT consists of a total of	6 sheets, including this cover s	eet.					
be (s	 This report is also accompanied by ANNEXES, i.e. sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications made before this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions under the PCT). These annexes consist of a total of sheets. 								
3. This r	eport ⊠	contains indications rela	ting to the following items:						
II		Priority							
III		-	pinion with regard to novelty, in	entive step and industrial appl	licability				
IV		Lack of unity of invention	on ,						
٧	☒		nder Article 35(2) with regard to ons suporting such statement	ovelty, inventive step or indus	strial applicability;				
VI		Certain documents cité	ed		,				
VII	\boxtimes	Certain defects in the in	nternational application						
VIII	×	Certain observations or	n the international application						
Date of sub	missio	on of the demand	Date of	ompletion of this report					
04/02/20	00		03.10.2	00					
Name and mailing address of the international preliminary examining authority: European Patent Office - P.B. 5818 Patentlaar NL-2280 HV Rijswijk - Pays Bas Tel. +31 70 340 - 2040 Tx: 31 651 epo nl Fax: +31 70 340 - 3016			818 Patentlaan 2 S Visen 51 epo nl	ed officer 1, A ne No. +31 70 340 2530	John SOCES FAIRLY COLD STORY				

INTERNATIONAL PRELIMINARY **EXAMINATION REPORT**

International application No. PCT/EP99/05147

 Basis of the repair 	port	repo	rt
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1.	Bas	is of the report						
1. This report has been drawn on the basis of (substitute sheets which have been furnished to the receiviresponse to an invitation under Article 14 are referred to in this report as "originally filed" and are not at the report since they do not contain amendments.):								
	Des	cription, pages:						
	1-4		as originally	filed				
	Cla	ims, No.:						
	1-6		as originally	filed				
2.	The	amendments have	e resulted in th	ne cancel	llation of:			
		the description,	pages:					
		the claims,	Nos.:					
		the drawings,	sheets:					
3.		This report has be considered to go b	en establishe peyond the dis	d as if (so sclosure a	come of) the amendments had not been made, since they have been as filed (Rule 70.2(c)):			
4.	Ado	litional observations	s, if necessan	y:				
v.					vith regard to novelty, inventive step or industrial supporting such statement			
1.	Sta	tement						
	Nov	velty (N)	Yes: No:	Claims Claims				
	Inve	entive step (IS)	Yes: No:	Claims Claims				

Claims 1-6

Claims

Yes: No:

Industrial applicability (IA)

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No. PCT/EP99/05147

2. Citations and explanations

see separate sheet

VII. Certain defects in the international application

The following defects in the form or contents of the international application have been noted:

see separate sheet

VIII. Certain observations on the international application

The following observations on the clarity of the claims, description, and drawings or on the question whether the claims are fully supported by the description, are made:

see separate sheet

Re Item V

Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

1.) In this report reference is made to the following documents, cited in the International Search Report:

D1: Patent Abstracts of Japan, Vol. 11, Nr. 286 (E-541), 16 September 1987, & JP-A-62084568

D2: Patent Abstracts of Japan, Vol. 10, Nr. 376 (E-464), 13 December 1986, & JP-A-61168271

D3: Patent Abstracts of Japan, Vol. 17, Nr. 434 (E-1412), 11 August 1993, & JP-A-5090624

The following document D4 was not cited in the International Search Report.

D4: Solar Energy Materials and Solar Cells, Vol. 43 (1996), pages 93-98

2.) The subject-matter of claim 1 meet the requirements of Art. 33(2)(3) PCT, as it is considered as new and inventive with respect to the cited state of the art. Indeed both documents D1 and D2 disclose a method of forming a solar cell by depositing a photovoltaically active layer on a support of a polymeric organic material having a glass transition temperature of from 90°C to 200°C (see D1, abstract and figure and D2, abstract). In D2 the deposition is carried out at a substrate temperature below the glass transition temperature of the polymer.

No cited document describes a step of annealing the deposited film for a period of 0.01 to 1 s at temperatures of at least 250°C, by means of a laser having an energy from 2 to 5000 W/mm², so that it is considered that claim 1 is new and inventive.

- 3.) Also the combination of the subject-matter of claim 1 with the additional features of the dependent claims 2 and 3 is considered as new and inventive (Art. 33(2)(3) PCT.
- 4.) The subject-matter of independent claim 4 does not meet the requirements of Art.

INTERNATIONAL PRELIMINARY International application No. PCT/EP99/05147 EXAMINATION REPORT - SEPARATE SHEET

33(2)(3) PCT, because it lacks novelty.

Indeed both documents D1 and D2 disclose a solar cell comprising one photovoltaically active layer on a support of a polymeric organic material having a glass transition temperature of from 90°C to 200°C (see D1, abstract and figure and D2, abstract). Therefore all features of claim 1 are known from D1 or D2 and consequently claim 4 is not novel.

5.) The subject-matter of claim 6, dependent on claim 4, is also known from D1 (see D1, abstract and figure).

Consequently this claim cannot add anything new to the subject-matter of claim 4, on which it depends (Art. 33(2)(3) PCT).

The subject-matter of claim 5, dependent on claim 4, is known from D3 (see D3, abstract and figure).

Consequently this claim cannot add anything inventive to the subject-matter of claim 4, on which it depends (Art. 33(3) PCT).

6.) All claims 1-6 meet the requirements of industrial applicability of Art. 33(4) PCT.

Re Item VII

Certain defects in the international application

Contrary to the requirements of Rule 5.1(a)(ii) PCT, the relevant background art disclosed in the documents D1, D2 and D3 are not mentioned in the description, nor are these documents identified therein.

Re Item VIII

Certain observations on the international application

- 1.) The subject-matter of claim 1 of the application does not satisfy the requirements of Art. 6 PCT.
- 1.1) Indeed in claim 1 a method of coating a polymeric material with a photovoltaic active layer is disclosed, without any specifications as to the kind of deposited material. In the description only thin semiconductor layers are disclosed. For the man skilled in the photovoltaic technology thin film materials are a class of materials with well defined properties (polycrystalline, microcrystalline or amorphous structure and a thickness of

INTERNATIONAL PRELIMINARY International application No. PCT/EP99/05147 EXAMINATION REPORT - SEPARATE SHEET

some microns), different from the thicker layers of monocrystalline devices. Following the description, page 1, lines 1-3 and the example given at page 4 the method of the invention relates only to the production of thin film semiconductor layers.

Therefore, in order for the claim to be fully supported by the description (Art. 6 PCT; PCT Preliminary Examination Guidelines, Section IV, III-6.1; PCT Gazette S-07/1998, 29 October 1998) only thin film of photovoltaically active materials should be claimed.

1.2) Moreover it appears that the claimed method could not be directly used for all kind of thin film materials known to the skilled man at the filing date of the application. Indeed considering the semiconductor material CuInSe₂ and related compounds (containing also the elements Ga, AI or S in the molecule) it seems that it is not possible to obtain a thin film of such material using the method of claim 1. Such a thin film deposition requires normally a selenization at high temperature and for a longer time. Referring to the teaching of document D4, a selenization at 400°C for one hour is required to form a thin film layer with the required stoichiometry (see D4, pages 93-95). For this reason a polyimide sheet was used as substrate material. Following the PCT Guidelines, Section IV, III-6.1-III-6.4 (PCT Gazette S-07/1998, 29 October 1998) generalizations are only admitted if supported by the description and if there is no reason to suppose that the invention cannot be worked through the whole of the field claimed.

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INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

Applicant's or ag	gent's file reference		See Notific	ation of Transmittal of International					
A-G 6564-PC	Э Јо	FOR FURTHER AC	TION Preliminary	Examination Report (Form PCT/IPEA/416)					
International app	ollcation No.	International filing date (a	lay/month/year)	Priority date (day/month/year)					
PCT/EP99/0	5147	20/07/1999		30/07/1998					
International Patent Classification (IPC) or national classification and IPC H01L31/18									
Applicant	·								
AGFA-GEVA	ERT NAAMLOZE VEN	NOOTSCHAP et al.							
This international preliminary examination report has been prepared by this International Preliminary Examining Authority and is transmitted to the applicant according to Article 36.									
2. This REP	ORT consists of a total of	6 sheets, including this	cover sheet.						
been (see l	 This report is also accompanied by ANNEXES, i.e. sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications made before this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions under the PCT). These annexes consist of a total of sheets. 								
3. This report contains indications relating to the following items:									
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	Priority Non-establishment of c	ninion with regard to no	velty inventive step	and industrial applicability					
IV =			vony, mironare crop	,					
V ⊠	Reasoned statement u		egard to novelty, inve ement	entive step or industrial applicability;					
VI □	Certain documents cite	ed							
VII ⊠	Certain defects in the in	nternational application							
VIII ⊠	Certain observations of	n the international applic	cation						
Date of submiss	sion of the demand		Date of completion of	this report					
04/02/2000 03.10.2000									



preliminary examining authority:

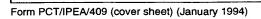
European Patent Office - P.B. 5818 Patentlaan 2

NL-2280 HV Rijswijk - Pays Bas

Tel. +31 70 340 - 2040 Tx: 31 651 epo nl Fax: +31 70 340 - 3016 Visentin, A

Authorized officer

Telephone No. +31 70 340 2530



Name and mailing address of the international

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

International application No. PCT/EP99/05147

I.	Basis of the report			Office in						
1.	This report has been drawn on the basis of (substitute sheets which have been furnished to the receiving Office in response to an invitation under Article 14 are referred to in this report as "originally filed" and are not annexed to the report since they do not contain amendments.):									
	Description, pages:									
	1-4	as originally file	ed							
	Claims, No.:									
	1-6	as originally fil	ed							
2.	The amendments have	e resulted in the	e cancella	ation of:						
	□ the description,	pages:								
	☐ the claims,	Nos.:								
	the drawings,	sheets:								
3	3. This report has been established as if (some of) the amendments had not been made, since they have be considered to go beyond the disclosure as filed (Rule 70.2(c)):									
4	. Additional observation	ns, if necessary	:							
`	/. Reasoned statemen applicability; citatio	nt under Article ns and explan	35(2) wi ations su	ith regard to novelty, inventive step or industrial upporting such statement						
1	. Statement									
	Novelty (N)	Yes: No:	Claims Claims	1-3,5 4,6						
	Inventive step (IS)	Yes: No:	Claims Claims	1-3 4-6						
	Industrial applicabilit	y (IA) Yes: No:	Claims Claims	1-6						

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

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see separate sheet

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INTERNATIONAL PRELIMINARY International application No. PCT/EP99/05147 EXAMINATION REPORT - SEPARATE SHEET

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INTERNATIONAL PRELIMINARY International application No. PCT/EP99/05147 EXAMINATION REPORT - SEPARATE SHEET

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WORLD INTELLECTUAL PROPERTY ORGANIZATION International Bureau



INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

51) International Patent Classification 7: H01L 31/18, 31/0392	A1	(11) International Publication Number: WO 00/07250 (43) International Publication Date: 10 February 2000 (10.02.00)
(22) International Application Number: PCT/EP (22) International Filing Date: 20 July 1999 ((30) Priority Data: 198 34 358.2 30 July 1998 (30.07.98) (71) Applicant (for all designated States exce AGFA-GEVAERT AG [DE/DE]; Kaiser-Wilhed D-51373 Leverkusen (DE). (72) Inventors; and (75) Inventors/Applicants (for US only): CRONE, K [DE/DE]; Im Bungert 4, D-53773 Henn LÖFFELMANN, Günter [DE/DE]; Am Dode D-51515 Kürten (DE). MODEMANN, Karl Heinrich-Heine-Strasse 39, D-53225 Bonn (DE Eberhard [DE/DE]; Königsberger Strasse 34, Burscheid (DE). SAUERTEIG, Wolfgang Walter-Flex-Strasse 1, D-51373 Leverkusen (DI (74) Common Representative: AGFA-GEVAER Kaiser-Wilhelm-Allee, D-51373 Leverkusen (D	20.07.5 Ipt U Im-All laus-Pe ef (D mberg [DE/D). KOO D-513 [DE/D 3). T	BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GI GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KC KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MI MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, S SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, Z ZW, ARIPO patent (GH, GM, KE, LS, MW, SD, SL, S: UG, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MI RU, TJ, TM), European patent (AT, BE, CH, CY, DE, DI ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OA: patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MI NE, SN, TD, TG). Published With international search report.

(57) Abstract

Organic polymeric films may serve as supporting materials for at least one photovoltaically active layer, if the supporting material consists of a polymeric material with a glass transition temperature of from 90 °C to 200 °C. The coating of the photovoltaically active layer is carried out at temperatures below the glass transition temperature and annealing is carried out at temperatures of at least 250° by means of a laser.

Intern. .al Application No PCT/EP 99/05147

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1	FOILS" JOURNAL OF CRYSTAL GROWTH, NL, NORTH-H		
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	PUBLISHING CO. AMSTERDAM, vol. 152, no. 3, page 150-157 XP000	0626678	
	TCEN: 0022-0240		
	the whole document		
	TOTALES OF JAPAN		4,6
X	PATENT ABSTRACTS OF JAPAN vol. 011, no. 286 (E-541),		
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-	uther documents are listed in the continuation of box C.	X Patent family members are lis	ted in annex.
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Interna al Application No PCT/EP 99/05147

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C.(Continue	ition) DOCUMENTS CONSIDERED TO BE RELEVANT	
Category °	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	PATENT ABSTRACTS OF JAPAN vol. 010, no. 376 (E-464), 13 December 1986 (1986-12-13) & JP 61 168271 A (SUMITOMO BAKELITE CO LTD;OTHERS: 01), 29 July 1986 (1986-07-29) abstract	4
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A	NISHIWAKI H ET AL: "DEVELOPMENT OF AN ULTRALIGHT, FLEXIBLE A-SI SOLAR CELL SUBMODULE", SOLAR ENERGY MATERIALS AND SOLAR CELLS, NL, ELSEVIER SCIENCE PUBLISHERS, AMSTERDAM, VOL. 37, NR. 3/04, PAGE(S) 295-306 XP000521870 ISSN: 0927-0248 cited in the application	
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Interns at Application No PCT/EP 99/05147

Patent document cited in search report		Publication date	Patent family member(s)	Publication date
	A	18-04-1987	JP 1946831 C JP 6071091 B	10-07-1995 07-09-1994
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INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

INTERNATIONAL AFFLICATION TODEIS			
(51) International Patent Classification 7:		(11) International Publication Number:	WO 00/07250
H01L 31/18, 31/0392	A1	(43) International Publication Date:	10 February 2000 (10.02.00)

DE

PCT/EP99/05147

(21) International Application Number:	PCT/EP99/05147
(22) International Filing Date:	20 July 1999 (20.07.99)

(71) Applicant (for all designated States except AGFA-GEVAERT AG [DE/DE]; Kaiser-Wilhelm-Allee, D-51373 Leverkusen (DE).

30 July 1998 (30.07.98)

(72) Inventors; and (75) Inventors/Applicants (for US only): CRONE, Klaus-Peter [DE/DE]; Im Bungert 4, D-53773 Hennef (DE). LÖFFELMANN, Günter [DE/DE]; Am Domberg 9, D-51515 Kürten (DE). MODEMANN, Karl [DE/DE]; Heinrich-Heine-Strasse 39, D-53225 Bonn (DE). KOCH, Eberhard [DE/DE]; Königsberger Strasse 34, D-51399 Burscheid (DE). SAUERTEIG, Wolfgang [DE/DE]; Walter-Flex-Strasse 1, D-51373 Leverkusen (DE).

AGFA-GEVAERT AG; (74) Common Representative: Kaiser-Wilhelm-Allee, D-51373 Leverkusen (DE).

(81) Designated States: AE, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZA, ZW, ARIPO patent (GH, GM, KE, LS, MW, SD, SL, SZ, UG, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG).

Published

With international search report.

(54) Title: METHOD OF PRODUCING SOLAR CELLS

(57) Abstract

(30) Priority Data:

198 34 358.2

Organic polymeric films may serve as supporting materials for at least one photovoltaically active layer, if the supporting material consists of a polymeric material with a glass transition temperature of from 90 °C to 200 °C. The coating of the photovoltaically active layer is carried out at temperatures below the glass transition temperature and annealing is carried out at temperatures of at least 250° by means of a laser.

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PCT/EP99/05147 WO 00/07250

Method of producing solar cells

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The invention relates to an economically improved method of producing thin-layer solar cells, e.g. CdTe solar cells (CdTe = cadmium telluride). CdTe is used below merely as an example for all thin-layer solar cells.

CdTe and CdTe/CdS solar cells may be produced by various methods (US-5 304 499), common to all of which is heat treatment at at least 575°C, to achieve adequate efficiency. These temperatures allow the use only of expensive types of glass as supports. The use of glass as a support has the disadvantage that glass panels may be coated with CdTe only in discontinuous manner, irrespective of the coating method selected.

US-5 304 499 describes a method in which coating is carried out at temperatures of only 480 to 520°C, it thus being possible to use cheap types of glass ("window glass").

To this end, it is necessary for the glass firstly to be provided with a transparent, electrically conductive layer, e.g. of doped tin oxide. This is followed by a thin cadmium sulfide layer (CdS), to which the light-sensitive CdTe layer is then applied by sublimation at 480 to 520°C.

The apparatus required for application of the CdTe layer is complex and expensive: support material and CdTe source are held in such a way by opposing graphite blocks, which are heated to the necessary temperature, that the CdTe source is located only 2 to 3 mm from the support surface. Sublimation is then effected in a 0.1 mbar inert gas atmosphere, e.g. a nitrogen, helium, argon or hydrogen atmosphere. Large areas of CdTe-coated material for producing solar cells cannot be produced economically in this way.

H. Nishiwaki et al, Solar Energy Materials and Solar Cells 37 (1995) 295 to 306 use a polyimide film as support because this material has sufficient heat resistance in

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comparison to polyethylene terephthalate (PET) and polyethylene naphthalate (PEN), because of its glass transition temperature of more than 500°C. Polyimide has the disadvantage to be insoluble in usual solvents and to be unable to be molten. It is therefore extremely difficult to be processed.

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The known methods do not permit the use of easily produceable films of polymeric organic materials as supports.

The object of the invention was the economic production of a support with a photovoltaically active layer, e.g. a CdTe layer.

A method was surprisingly found, which permits the use of flexible polymeric films for coating with CdTe and annealing, without the polymeric supporting material being damaged by the high temperatures. In this way, a starting material is obtained for high efficiency solar cells.

The invention therefore provides a method of coating organic polymeric supporting materials with CdTe and annealing the CdTe layer of the materials thus coated, characterised in that the supporting material consists of a polymeric material with a glass transition temperature of from 90°C to 200°C and coating of the CdTe layer is carried out at temperatures below the glass transition temperature and annealing at temperatures of at least 250°C, in particular 400 to 600°C, by means of a laser for 0.01 to 1 s with an energy of 2 to 5000 watt per mm².

25 Preferably the supporting material is at least 60 μ m, in particular 90 to 120 μ m, thick and the CdTe layer is at most 30 μ m, in particular 2 to 7 μ m, thick.

Coating is carried out for example with an aqueous or solvent-containing CdTe suspension.

The material is then dried. Suitable coating methods are, for example, flooding and knife coating.

Annealing may be carried out several times; cooling phases are preferably provided between pairs of annealing steps.

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Suitable polymers are PET and PEN. Prior to coating, the polymeric supporting material may be provided with a substrate layer, e.g. of indium-tin oxide, which improves the adhesion of the CdTe layer. The substrate layer should be transparent and electrically conductive.

Suitable lasers are, for example, argon lasers and yag lasers with frequency duplication.

Organic polymeric supporting materials are flexible and thus permit continuous coating using a suitable coating method.

It is especially advantageous for the CdTe particles to be particularly fine, in particular in the form of so-called nano-particles, i.e. particles whose average diameter lies in the nanometric range and amounts, for example, to from 3 to 5 nm.

In this case, it is expedient for an agent to be present during production of the nanoparticles which prevents agglomeration of the nanoparticles, e.g. tributyl-phosphane.

The invention also provides a solar cell comprising at least one CdTe layer at most 30 μm thick on a support, characterised in that the support is a polymeric organic material at least 60 μm thick and having a glass transition temperature of at least 90°C.

Owing to its flexibility, the polymeric organic support permits continuous coating by means of a coater, for example a meniscus or curtain coater, as known from the coating of photographic films.

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A film of PEN 100 μm thick and 100 cm wide is coated continuously with a suspension containing a dispersant and 31 g of cadmium telluride per litre. The coated film is then dried and the layer applied exhibits a dry layer thickness of 5 μm.

The film is annealed as follows:

The entire surface is irradiated with an Ar ion laser (wavelength 514 nm; power 7 W) with a focal point of 50 μm. The temperature is adjusted at from 400 to 450°C.

After annealing, the film exhibits light-dependent electrical resistance and is thus suitable for the production of a photovoltaic cell.

The supporting material is not damaged by exposure to the laser.

Claims

1. A method of coating organic polymeric supporting materials with at least one photovoltaically active layer and annealing the materials thus coated, characterised in that the supporting material consists of a polymeric material with a glass transition temperature of from 90°Cto 200°C. Coating is carried out at temperatures below the glass transition temperature and annealing at temperatures of at least 250°, in particular 400 to 600°C, by means of a laser for 0.01 to 1 s with an energy to 2 to 5000 watt per mm².

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- 2. A method according to claim 1, wherein the supporting material is at least $60 \mu m$ thick and the photovoltaic layer is at most $30 \mu m$ thick.
- 3. A method according to claim 1, wherein the supporting material is of polyethylene terephthalate or polyethylene naphthalate.
 - 4. A solar cell comprising at least one photovoltaically active layer on a support, characterised in that the support is a polymeric organic material having a glass transition temperature of from 90°C to 200°C.

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- 5. A solar cell, according to claim 4, characterised in that the photovoltaically active layer comprises cadmium telluride.
- 6. A solar cell according to claim 4, characterised in that the support consists of polyethylene terephthalate or polyethylene naphthalate.



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INTERNATIONAL SEARCH REPORT

(PCT Article 18 and Rules 43 and 44)

Applicant's or agent's file reference A-G 6564-PC Jo FOR FURTHER see Notification of Transmittal of International Search Report (Form PCT/ISA/220) as well as, where applicable, item 5 below								
International application No.	International filing date (day/month/year	r) (Earliest) Priority Date (day/month/year)						
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This International Search Report has bee according to Article 18. A copy is being tra	n prepared by this International Searching ansmitted to the International Bureau.	Authority and is transmitted to the applicant						
This International Search Report consists X It is also accompanied by	of a total of sheets. a copy of each prior art document cited in	n this report.						
Basis of the report a. With regard to the language, the language in which it was filed, un	international search was carried out on the less otherwise indicated under this item.	ne basis of the international application in the						
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2. Certain claims were four 3. Unity of invention is lace	und unsearchable (See Box I). cking (see Box II).							
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5. With regard to the abstract,								
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6. The figure of the drawings to be pub	olished with the abstract is Figure No.							
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A. CLASSIFICATION OF SUBJECT MATTER IPC 7 H01L31/18 H01L31/0392										
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Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched										
Electronic data base consulted during the international search (name of data base and, where practical, search terms used)										
C. DOCUMENTS CONSIDERED TO BE RELEVANT										
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"A" document defining the general state of the art which is not considered to be of particular relevance or priority date and not in conflict with the application but clied to understand the principle or theory underlying the invention										
"E" earlier document but published on or after the international "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to										
"L" document which may throw doubts on priority claim(s) or involve an inventive step when the document is taken alone which is cited to establish the publication date of another "Y" document of particular relevance; the claimed invention										
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1	other means ments, such combination being obvious to a person skilled in the art.									
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	NL – 2280 HV Rijswijk Tel. (+31–70) 340–2040, Tx. 31 651 epo nl,	Visentin, A								
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